

## **DBL201S THRU DBL207S**

# **SINGLE-PHASE GLASS PASSIVATED SILICON SURFACE MOUNT BRIDGE RECTIFIER**

#### **Reverse Voltage - 50 to 1000 V**

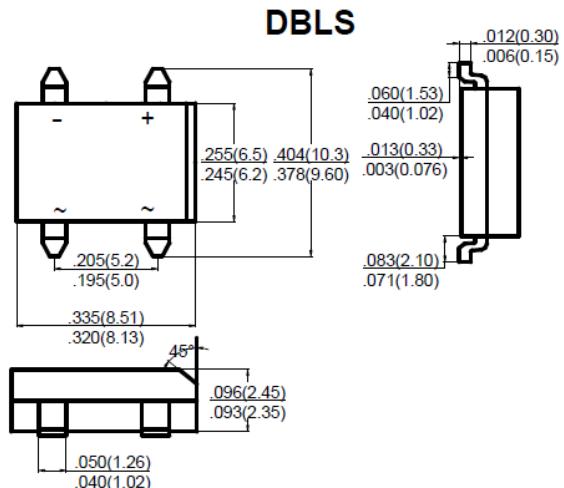
## **Forward Current - 2 A**

## Features

- High surge overload rating of 60 A peak
  - Ideal for printed circuit board
  - Low forward voltage drop
  - Glass passivated chip junction

## Mechanical Data

- Case: Molded plastic, DBLS
  - Epoxy: UL 94V-0 rate flame retardant
  - Terminal: Leads solderable per MIL-STD-202,  
method 208 guaranteed
  - Mounting position: Any

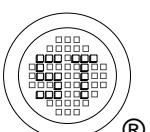


#### **Dimensions in inches and (millimeters)**

### **Maximum Ratings and Electrical Characteristics**

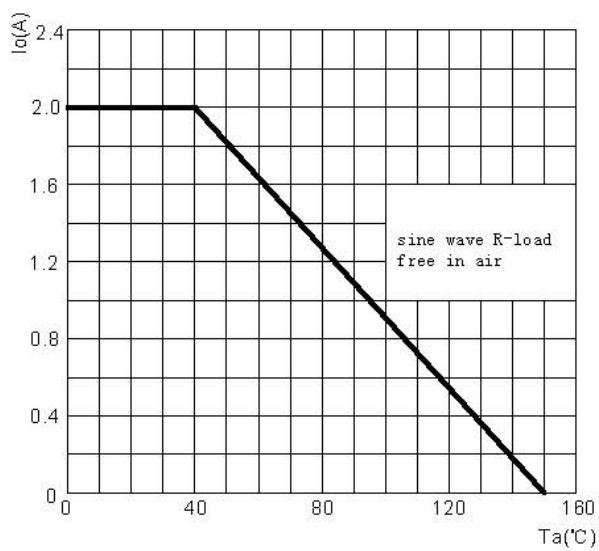
Ratings at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Parameter	Symbols	DBL201S	DBL202S	DBL203S	DBL204S	DBL205S	DBL206S	DBL207S	Units
Maximum Recurrent Peak Reverse Voltage	V <sub>RRM</sub>	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	V <sub>RMS</sub>	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V <sub>DC</sub>	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current at T <sub>A</sub> = 40 °C <sup>2)</sup>	I <sub>(AV)</sub>				2				A
Peak Forward Surge Current 8.3 ms Single Half-sine-wave Superimposed on Rated Load (JEDEC Method)	I <sub>FSM</sub>				60				A
Maximum Forward Voltage at 2 A DC	V <sub>F</sub>				1.1				V
Maximum Reverse Current at Rated DC Blocking Voltage	I <sub>R</sub>				10				µA
Typical Thermal Resistance	R <sub>θJA</sub>				68				°C/W
Typical Thermal Resistance	R <sub>θJL</sub>				15				°C/W
Operating and Storage Temperature Range	T <sub>j</sub> , T <sub>stg</sub>				- 55 to + 150				°C

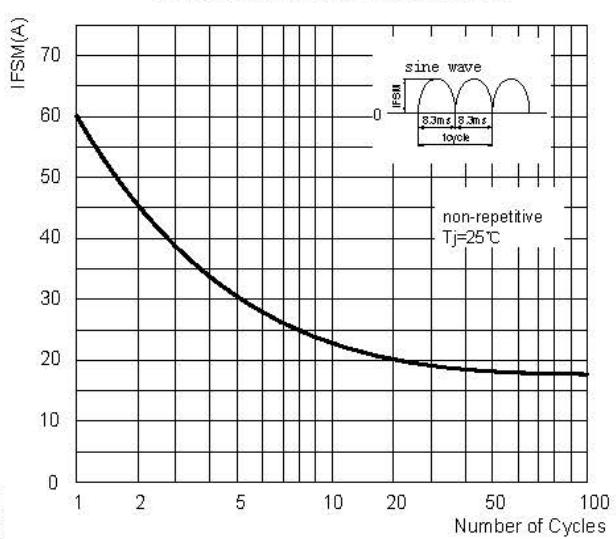


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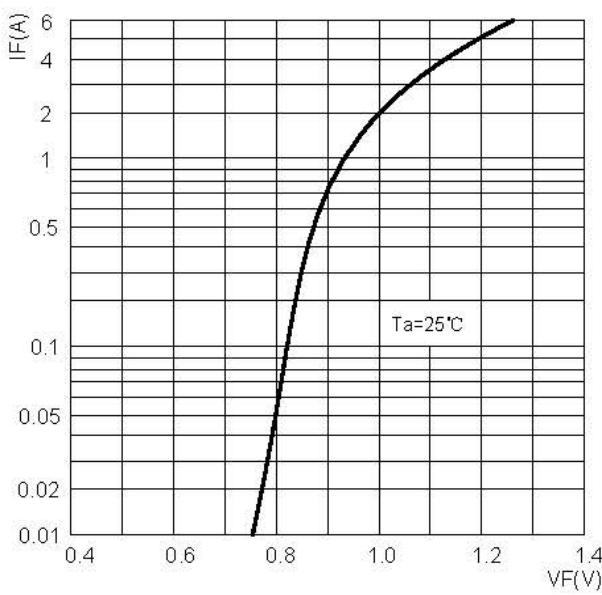
**FIG1:Io-Ta Curve**



**FIG2: Surge Forward Current Capability**



**FIG3: Forward Voltage**



**FIG4: Typical Reverse Characteristics**

